

Supporting Information

Electron-Beam Irradiation Enables Concurrent Thermoelectric and Mechanical Enhancement in Commercial p -Type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$

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Theoretical Calculation.

The thermoelectric transport properties with the Single Parabolic Band (SPB) framework were calculated using standard expressions:¹

Lorentz number (L):

$$L = \frac{k_B^2 3F_0 F_2 - 4F_1^2}{e^2 F_0^2} \quad (S1)$$

Seebeck coefficient (S):

$$S = \frac{k_B}{e} \left[\frac{\left(r + \frac{5}{2}\right) F_r + \frac{3}{2}(\eta)}{\left(r + \frac{3}{2}\right) F_r + \frac{1}{2}(\eta)} - \eta \right] \quad (S2)$$

Fermi Energy (F_j):

$$F_j(\eta) = \int_0^\infty \frac{\xi^j d\xi}{1 + e^{(\xi - \eta)}} \quad (S3)$$

Effective mass (m^*):

$$m^* = \frac{h^2}{2k_B T} \left(\frac{n}{4\pi F_{1/2}(\mu)} \right)^{\frac{2}{3}} \quad (S4)$$

Here, k_B denotes the Boltzmann constant, e represents the electron charge, r indicates the scattering factor, η signifies the bonding potential, h stands for Planck's constant, and T represents the absolute temperature.

The weighted mobility (μ_w) is given by the following expression:²

$$\mu_w = \frac{331}{\rho} \left(\frac{T}{300} \right)^{\frac{3}{2}} \left[\frac{\exp\left(\frac{|S|}{k_B/e} - 2\right)}{1 + \exp\left[-5\left(\frac{|S|}{k_B/e} - 1\right)\right]} + \frac{\frac{3|S|}{\pi^2 k_B/e}}{1 + \exp\left[5\left(\frac{|S|}{k_B/e} - 1\right)\right]} \right] \quad (S5)$$

To compare thermoelectric performance across finite temperature intervals, the average power factor (PF_{ave}) and average ZT_{ave} are defined as:

$$PF_{avg} = \frac{\int_{T_c}^{T_h} PF dT}{T_h - T_c} \quad (S6)$$

$$ZT_{avg} = \frac{\int_{T_c}^{T_h} ZT dT}{T_h - T_c} \quad (S7)$$

For the *p*-type Bi_{0.5}Sb_{1.5}Te₃ alloy studied here, bipolar diffusion becomes significant only above ~375 K. Therefore, at low temperatures (300-350 K), $\kappa_{\text{ph}} + \kappa_{\text{b}} \approx \kappa_{\text{ph}}$. The lattice thermal conductivity (κ_{ph}) in this range was fitted to the empirical form: $\kappa_{\text{ph}} = aT^{-1} + b$,³ where *a* and *b* are fitting parameters (Table S2). This fit was extrapolated up to 503 K to estimate the full-range lattice contribution (κ_{ph}) and the calculated electronic thermal conductivity (κ_{ele}) from the experimentally measured total thermal conductivity (κ_{tot}).

Table S1. Elemental composition of *p*-type Bi_{0.5}Sb_{1.5}Te₃ samples obtained from EDS analysis of the regions shown in Figure. 3, before and after electron-beam irradiation.

Samples Name (<i>p</i> -type Bi _{0.5} Sb _{1.5} Te ₃)	Bi (at%)	Sb (at%)	Te (at%)
Pristine	8.7	32.6	58.7
100 kGy	8.6	32.5	58.9
400 kGy	8.9	32.2	58.9
700 kGy	9.1	32.1	58.8
1000 kGy	8.6	32.3	59.1

Table S2. Fitting parameters (a and b) for the lattice thermal conductivity (κ_{ph}) of commercial p -type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ samples (pristine, 100, 400, 700, and 1000 kGy) over 303-503 K, using the relation $\kappa_{\text{ph}} = aT^{-1} + b$.

	p - $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ Sample Designation				
	Pristine	100 kGy	400 kGy	700 kGy	1000 kGy
a	50.04	16.21	14.15	17.62	12.46
b	0.46	0.52	0.438	0.53	0.49

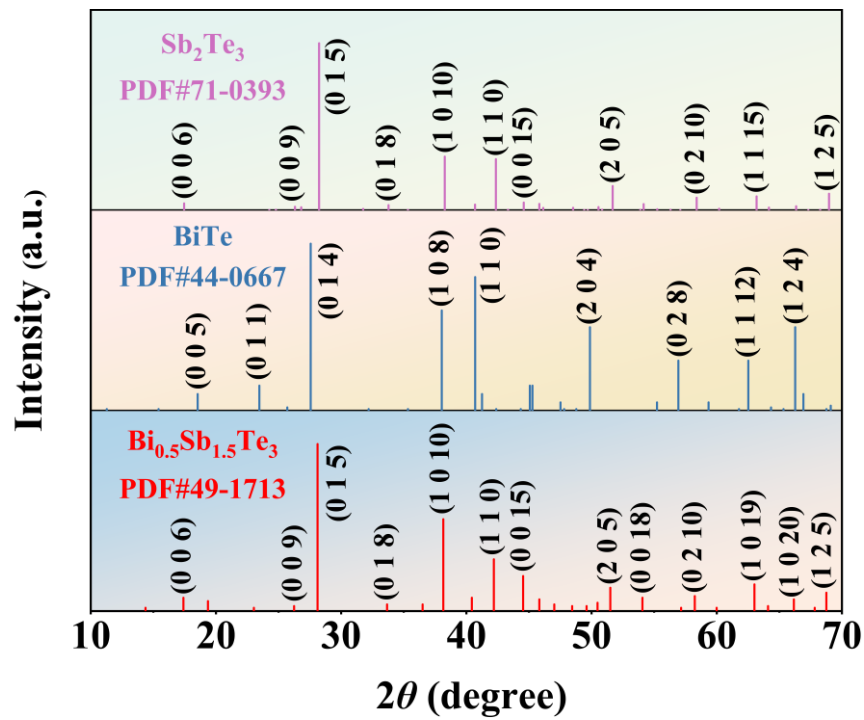


Fig. S1. Reference Powder Diffraction File (PDF) cards for the constituent phases: Sb_2Te_3 , BiTe , and the $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ alloy used in this study.

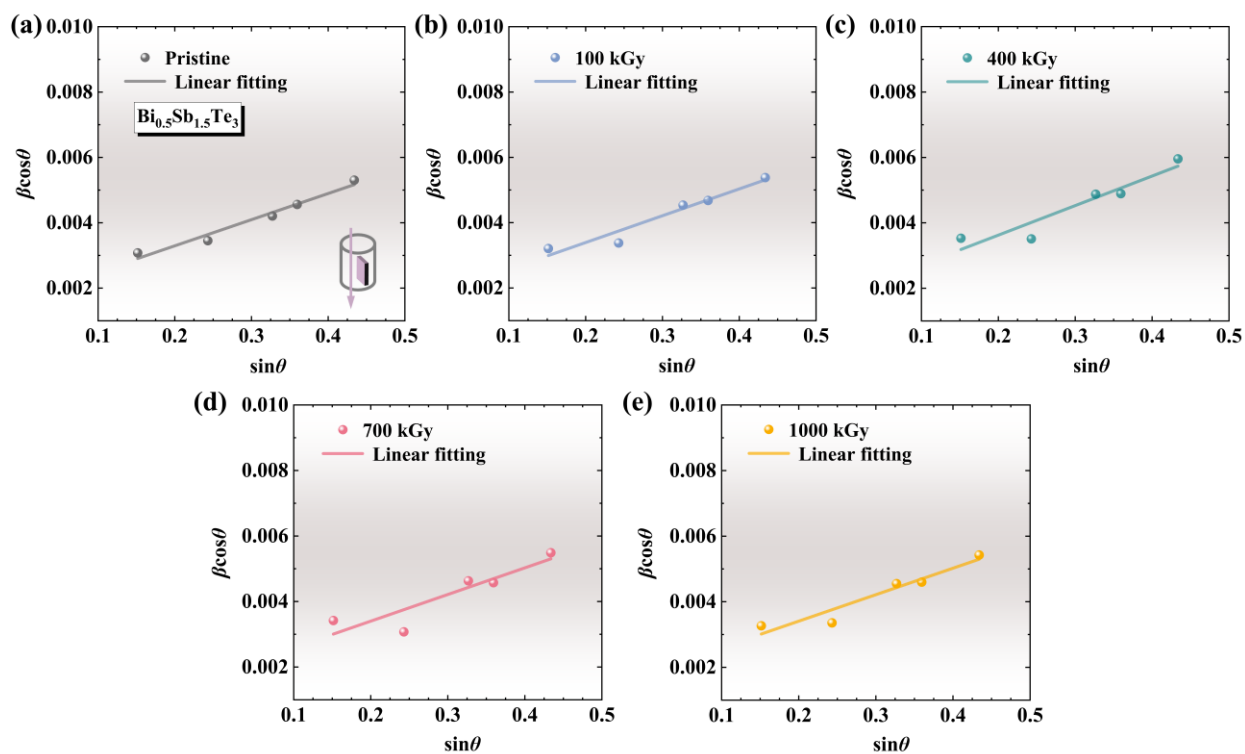


Fig. S2. Williamson-Hall plots of $\beta \cos \theta$ versus $\sin \theta$ for the commercially available p -type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ samples, used to evaluate lattice microstrain and crystallite size.

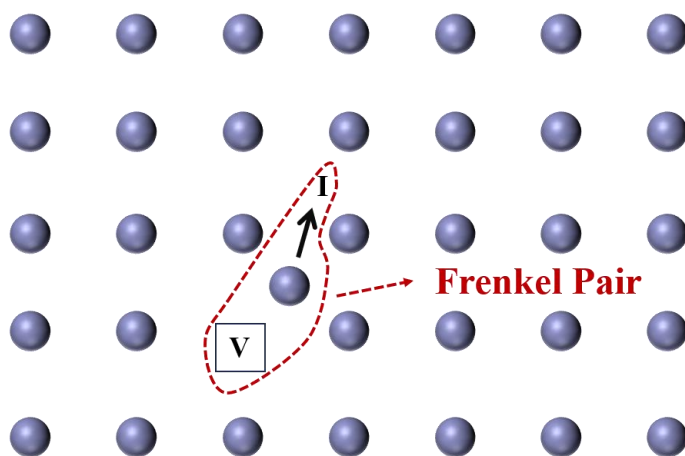


Fig. S3. Schematic illustration of vacancy-interstitial (Frenkel) pairs in the crystal lattice of p -type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$.

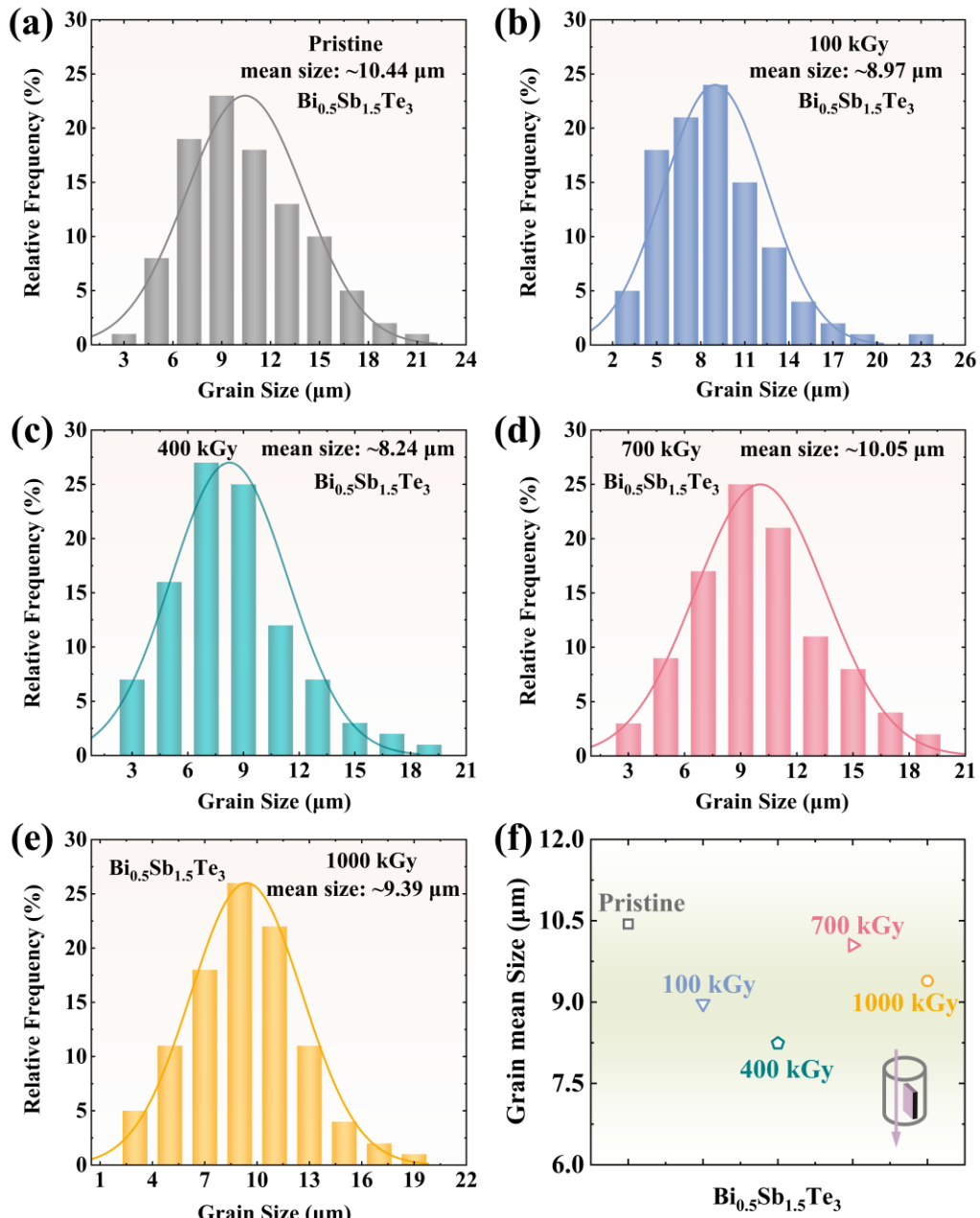


Fig. S4. Statistical analysis of grain size from fracture surfaces of *p*-type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ before and after electron-beam irradiation. Panels (a)-(e) correspond to the pristine, 100, 400, 700, and 1000 kGy samples, respectively, consistent with the SEM images shown in Figure. 3. Panel (f) compares the grain size distributions extracted from (a)-(e). The inset indicates that the fracture surfaces are parallel to the hot-pressing direction.

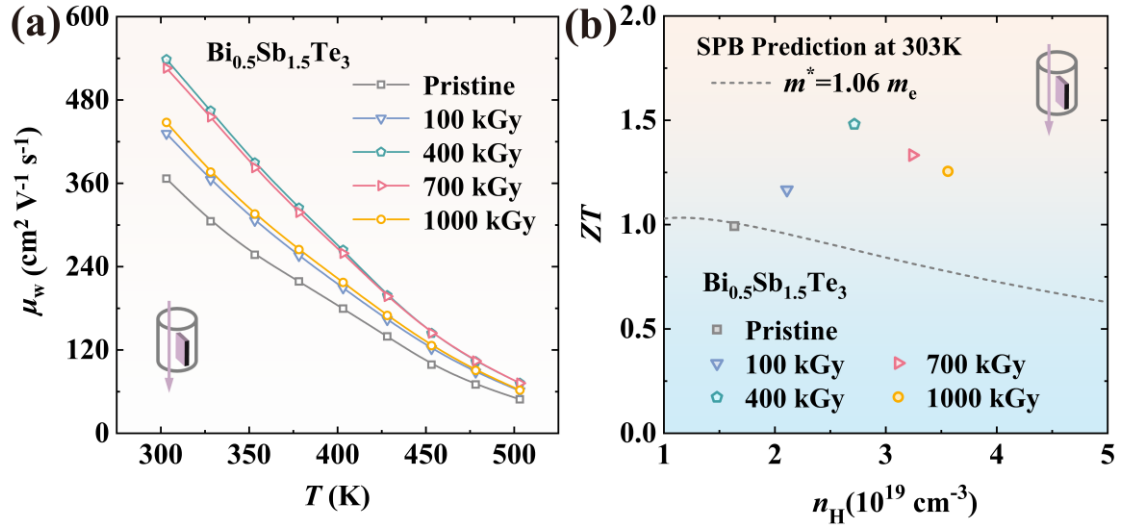


Fig. S5. (a) Temperature dependence of the weight mobility (μ_w) for *p*-type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ samples: pristine, 100, 400, 700, and 1000 kGy. (b) Room-temperature ZT as a function of carrier concentration (n_H), analyzed using the single parabolic band (SPB) model.

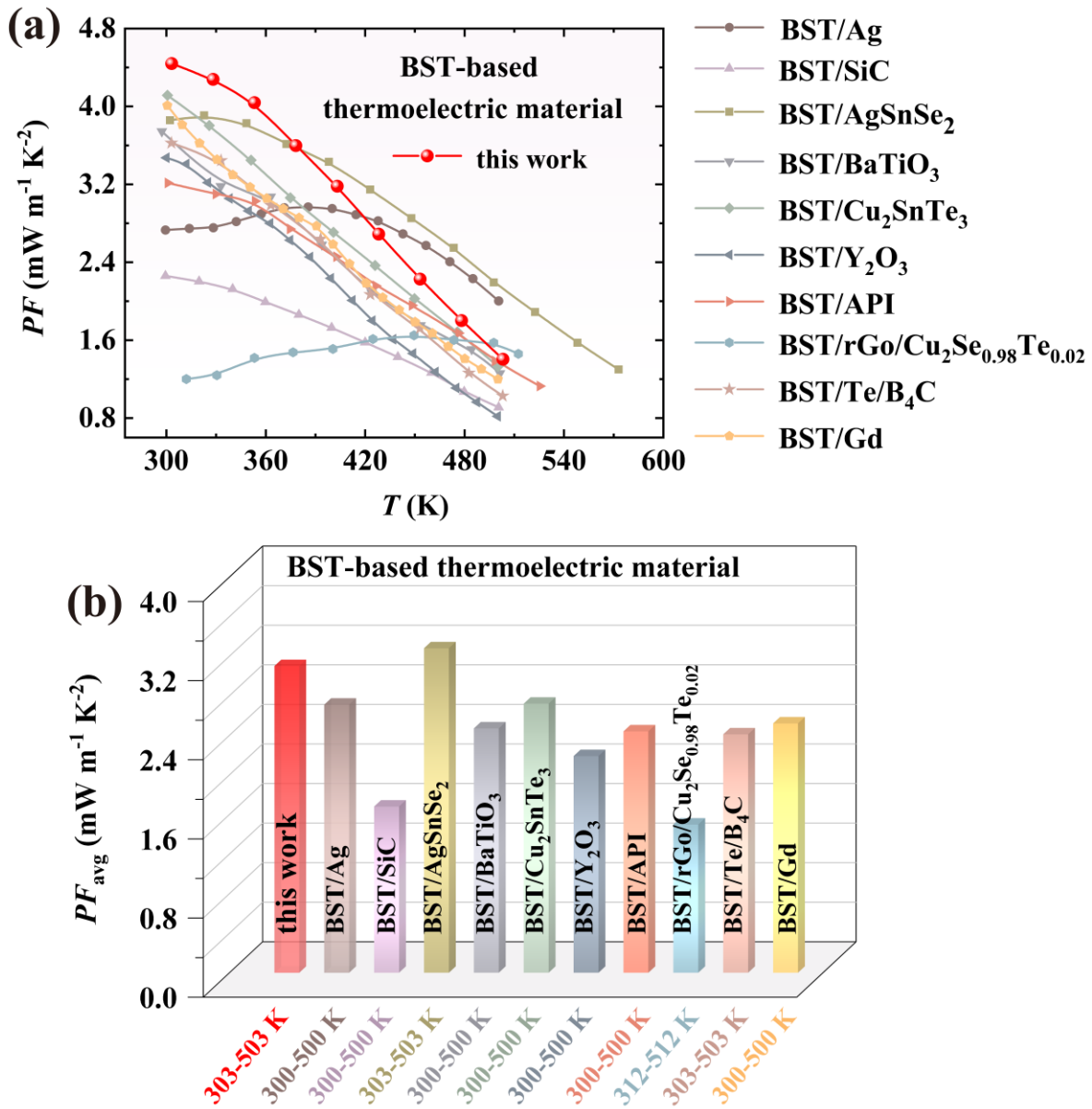


Fig. S6. Literature-reported power factor of BST-based optimized via interfacial engineering. (a) Temperature-dependent PF . (b) Average PF_{avg} over 303-503 K temperature range. References⁴⁻¹³ correspond to previous studies employing various interface engineering strategies.

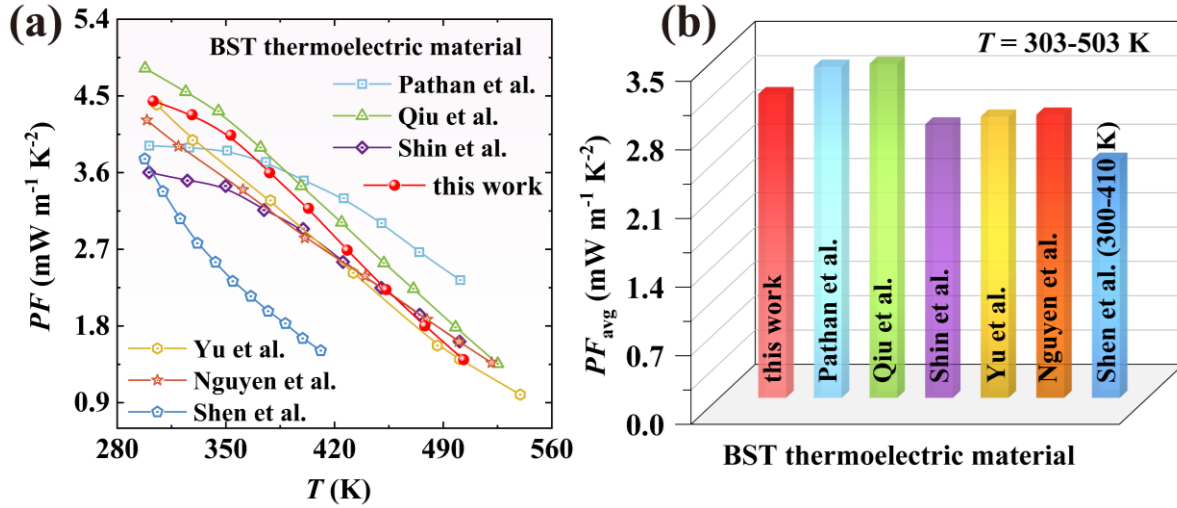


Fig. S7. Literature summary of p -type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ optimized via various processing strategies.¹⁴⁻¹⁹ (a) Temperature-dependent PF . (b) PF_{avg} over 303-503 K temperature range.

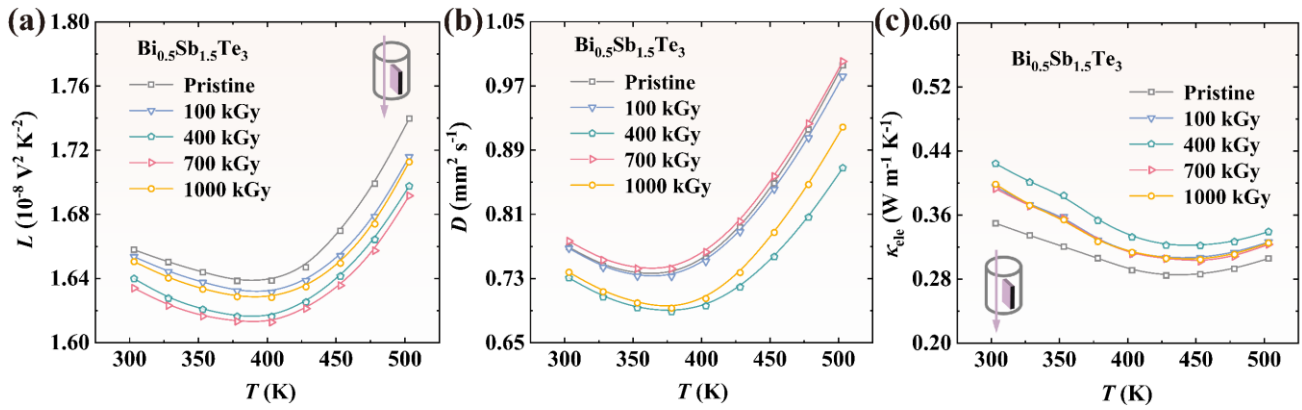


Fig. S8. Temperature dependence of key transport parameters for commercial p -type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ samples (pristine, 100, 400, 700, and 1000 kGy) before and after electron-beam irradiation: (a) Lorentz number (L), (b) thermal diffusion coefficient (D), and (c) electronic thermal conductivity (κ_{ele}).

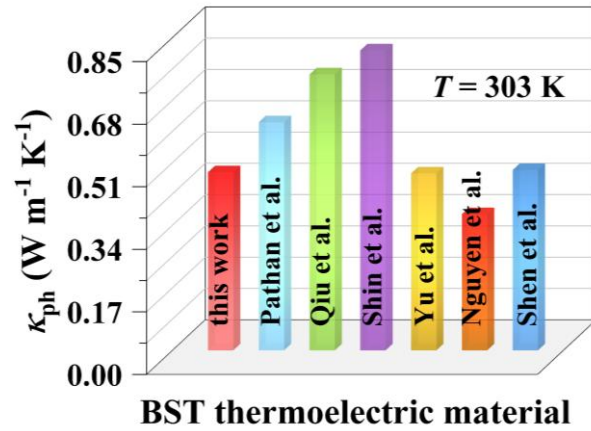


Fig. S9. Summary of reported room-temperature lattice thermal conductivity (κ_{ph}) for *p*-type $Bi_{0.5}Sb_{1.5}Te_3$ prepared via various optimized processing routes.¹⁴⁻¹⁹

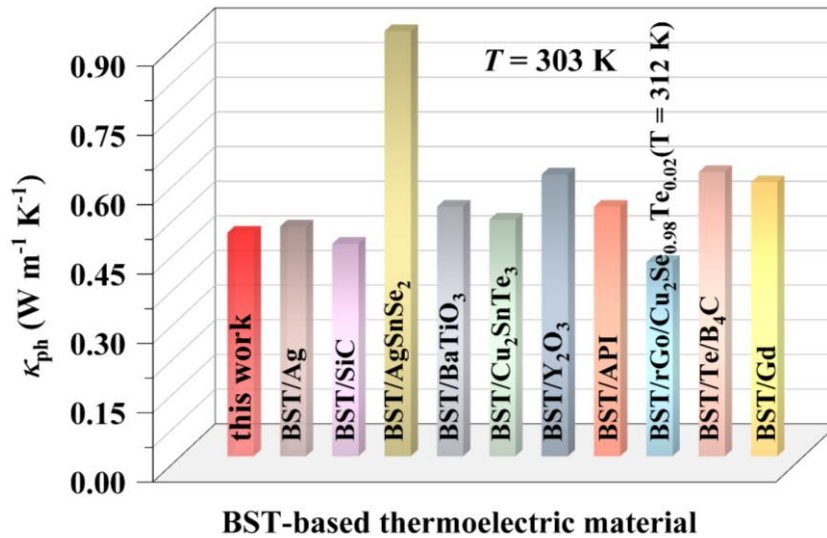


Fig. S10. Summary of reported room-temperature κ_{ph} for *p*-type $Bi_{0.5}Sb_{1.5}Te_3$ /secondary phase composites.⁴⁻¹³

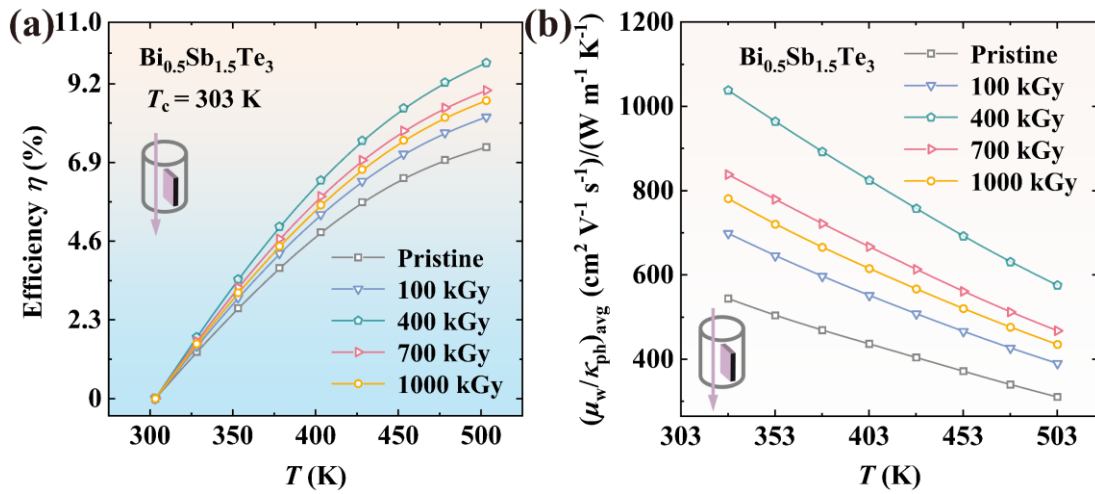


Fig. S11. Temperature-dependent theoretical thermoelectric conversion efficiency (η) and weighted mobility to lattice thermal conductivity ratio (μ_w/κ_{ph}) for commercial p -type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ samples before and after electron-beam irradiation.

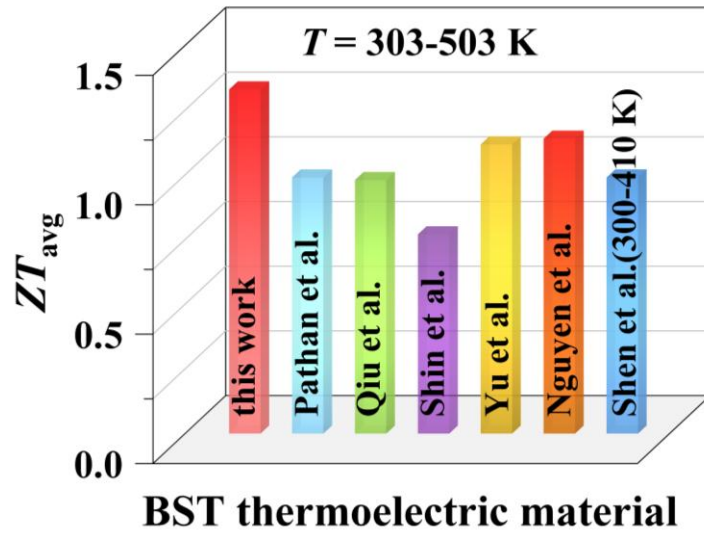


Fig. S12. Summary of reported average ZT_{avg} over 303-503 K for p -type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ prepared via various optimized processing techniques.¹⁴⁻¹⁹

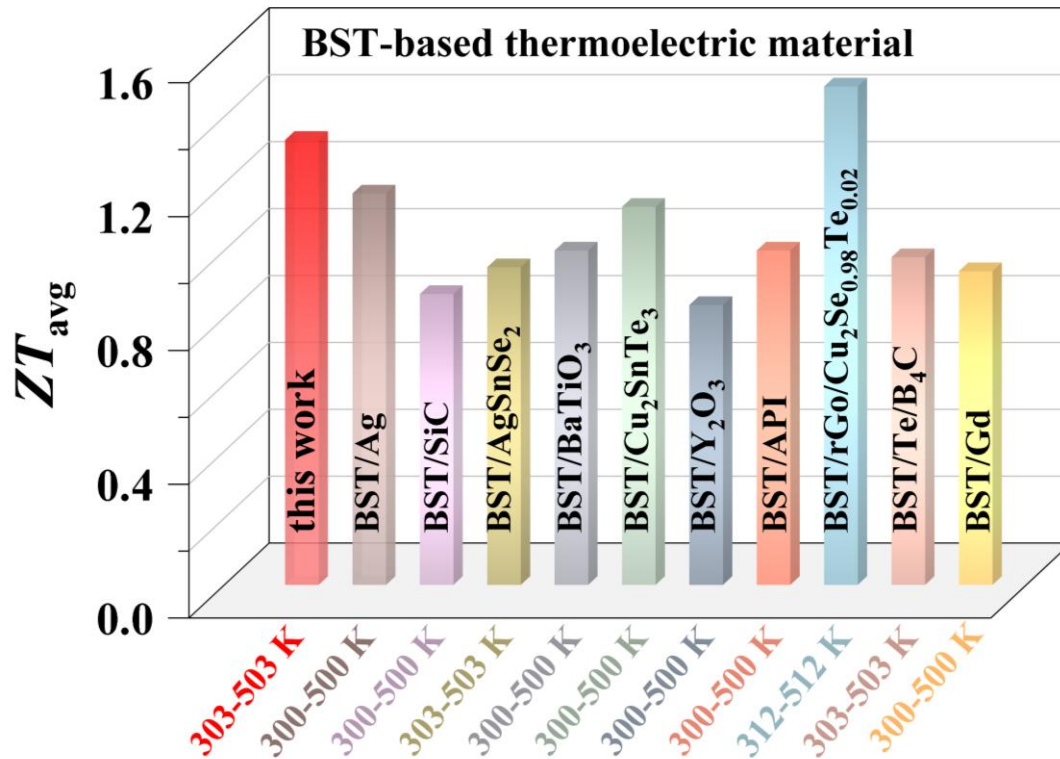


Fig. S13. Compilation of reported average ZT_{avg} over 303-503 K for p -type $\text{Bi}_{0.5}\text{Sb}_{1.5}\text{Te}_3$ /secondary phase composites from previous studies.⁴⁻¹³

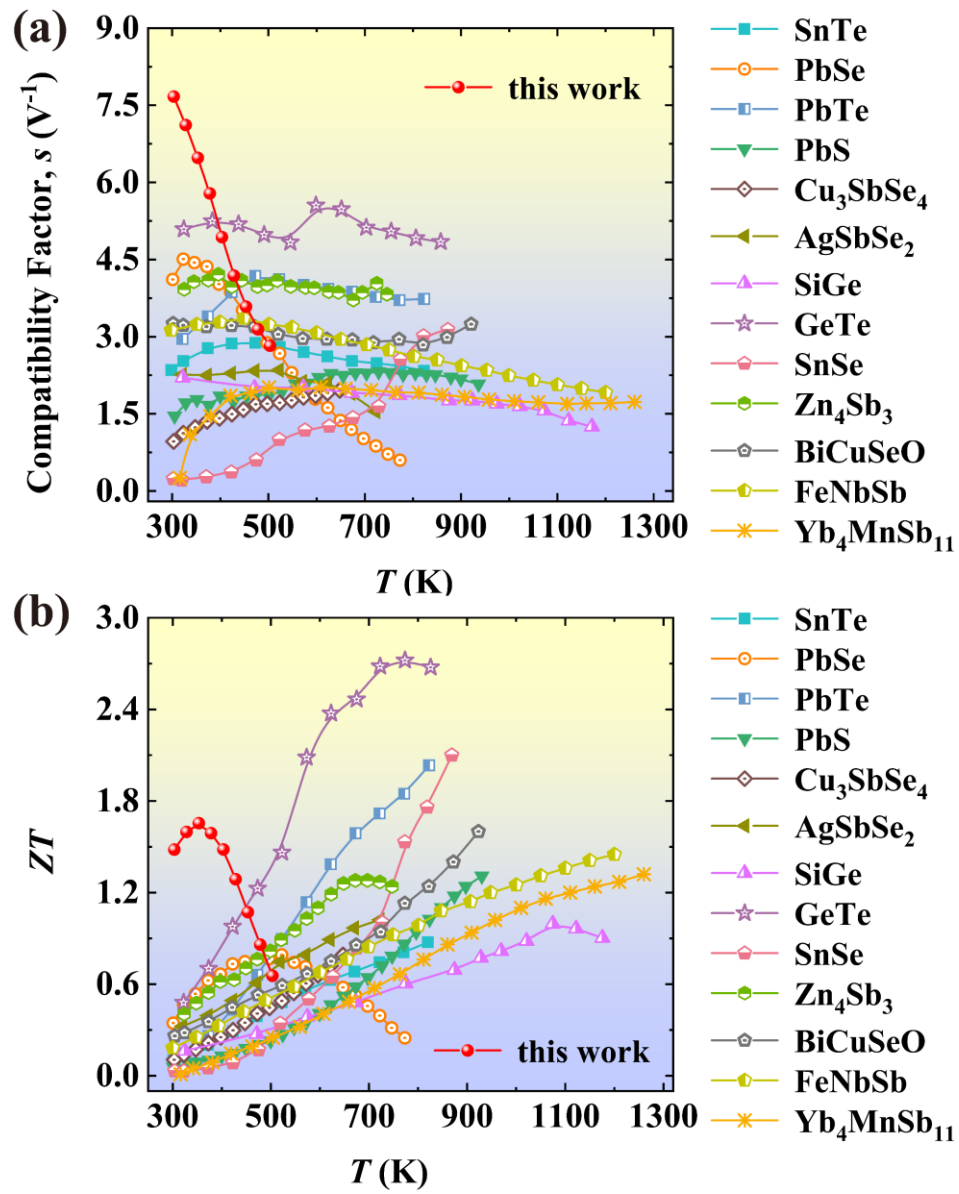


Fig. S14. Temperature dependence of (a) compatibility factor (s) and (b) ZT for representative p -type thermoelectric materials.²⁰⁻³²

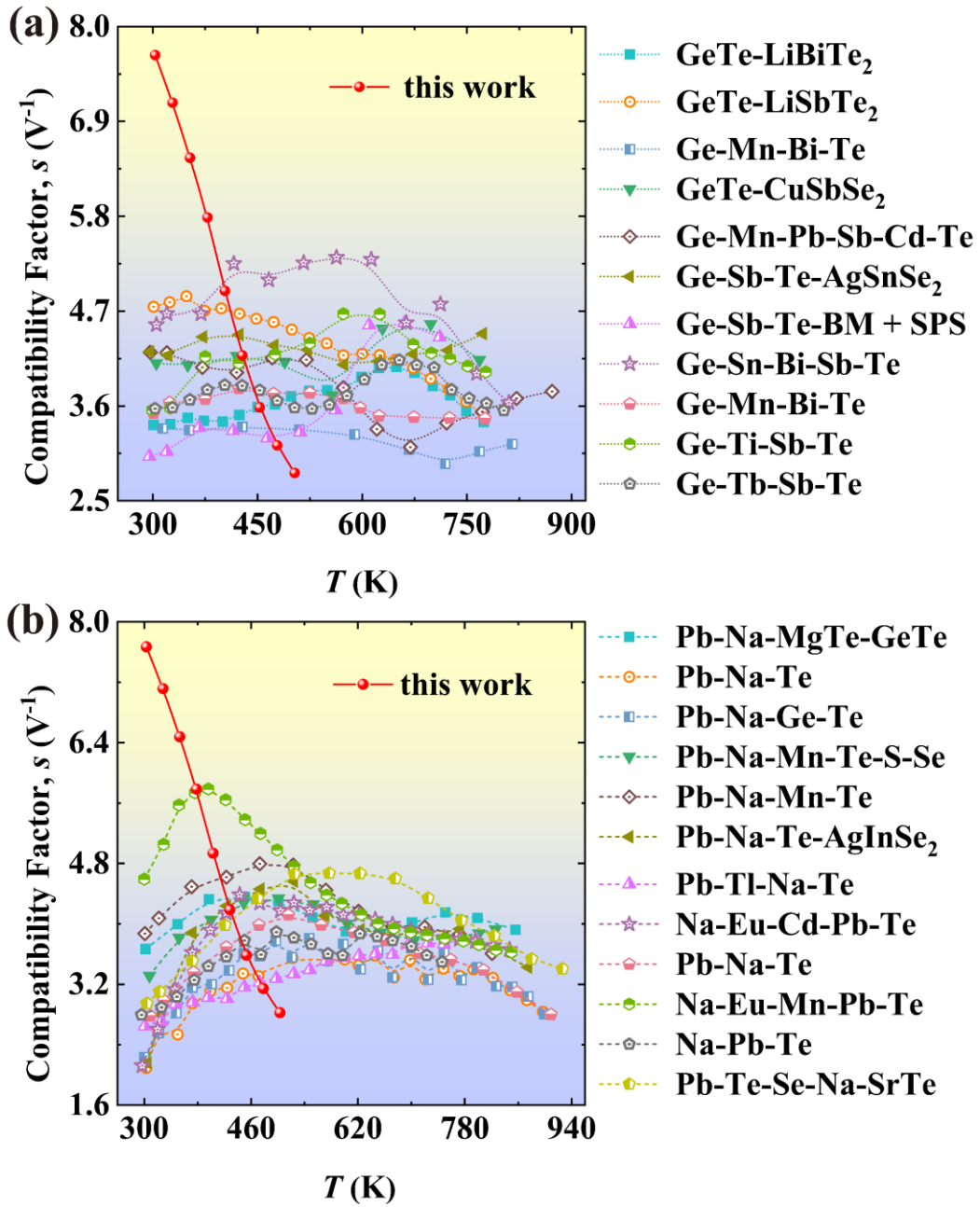


Figure S15. Temperature-dependent compatibility factor of representative high-performance materials: (a) cubic

GeTe³³⁻⁴³ and *p*-type PbTe.⁴⁴⁻⁵⁴

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